



## B320AF/B330AF

#### 3.0A SCHOTTKY BARRIER RECTIFIER

### **Product Summary**

#### B320AF/B330AF

Product	V <sub>RRM</sub> (V)	I <sub>0</sub> (A)	V <sub>F(MAX)</sub> (V) @ +25°C	I <sub>R(MAX)</sub> (mA) @ +25°C
B320AF	20	3	0.50	0.20
B330AF	30	3	0.50	0.20

## **Description and Applications**

The Schottky providing low  $V_F$  and excellent reverse leakage stability at high temperatures, this device is ideal for use in general rectification applications such as:

#### Boost Diodes

- Blocking Diodes
- Recirculating Diodes

### **Features and Benefits**

- Reduced Low Forward Voltage Drop (V<sub>F</sub>); Better Efficiency and Cooler Operation
- Reduced High-temperature Reverse Leakage; Increased Reliability against Thermal Runaway Failure in High Temperature Operation
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### **Mechanical Data**

- Case: SMAF
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 <sup>(3)</sup>
- Polarity: Cathode Band
- Weight: 0.036 grams (Approximate)

SMAF

Top View

## Ordering Information (Note 4)

Part Number	Case	Packaging
B320AF-13	SMAF	10,000/Tape & Reel
B330AF-13	SMAF	10,000/Tape & Reel

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

 See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**

Notes:



B3XXAF = Product Type Marking Code, ex: B320AF )'' = Manufacturers' Code Marking YWW = Date Code Marking Y = Last Digit of Year (ex: 7 for 2017) WW = Week Code (01 to 53)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	B320AF	B330AF	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>RM</sub>	20	30	v
Average Rectified Output Current	lo		3	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	80		А

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Ambient (Note 5)	R <sub>0JA</sub>	85	°C/W
Typical Thermal Resistance Junction to Case (Note 5)	R <sub>0JC</sub>	45	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

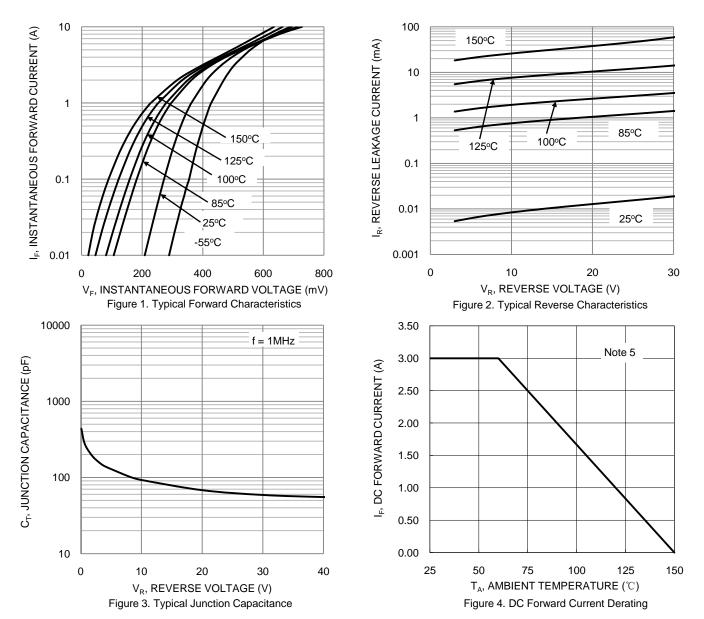
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Forward Voltage Drop		V <sub>F</sub>	_	0.46 0.40	0.50	V	I <sub>F</sub> = 3A, T <sub>J</sub> = +25°C I <sub>F</sub> = 3A, T <sub>J</sub> = +125°C
Leakage Current (Note 6)	B320AF B330AF	I <sub>R</sub>		0.02 12 0.03 14.0	0.20 — 0.20 —	mA	$ \begin{split} V_{R} &= 20V, \ T_{J} = +25^{\circ}C \\ V_{R} &= 20V, \ T_{J} = +125^{\circ}C \\ V_{R} &= 30V, \ T_{J} = +25^{\circ}C \\ V_{R} &= 30V, \ T_{J} = +125^{\circ}C \end{split} $
Typical Capacitance		Ст	—	140	—	pF	$V_R = 4.0V$ , f = 1MHz

Notes:

5. Device mounted on FR-4 substrate, 0.4"\*0.5", 2oz, single-sided, PC boards with 0.2"\*0.25" copper pad.
6. Short duration pulse test used to minimize self-heating effect.



## B320AF/B330AF



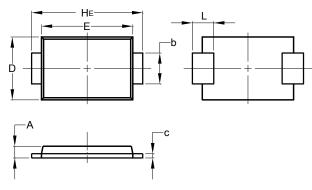
B320AF/B330AF Document number: DS39623 Rev. 2 - 2



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

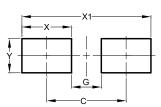
NEW PRODUCT



	SMAF					
Dim	Min	Max				
Α	0.90	1.10				
b	1.25	1.65				
С	0.10	0.40				
D	2.25	2.95				
E	3.95	4.60				
H <sub>E</sub> 4.80 5.60		5.60				
L	0.50	1.50				
All Di	All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	4.00
G	1.50
Х	2.50
X1	6.50
Y	1.70

SMAF

SMAF



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